



Article Dead-Time Effect in Inverters on Wireless Power Transfer

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Abstract: This paper presents a comprehensive analysis of the dead-time effects in wireless power transfer systems based on LCC-S topology. In these systems operating at high frequencies, the ratio of dead-time versus the operating period becomes critical, and the dead-time issue can cause certain problems regarding power quality, efficiency, and output voltage ripple. The impact of input quantities such as voltage and switching frequency on the efficiency and output power of the LCC-S-tuned WPT system was also investigated. The optimal combination of these parameters used to achieve the maximum efficiency for a target output power and to set the appropriate value of the dead time were determined by running multiple simulations using the MATLAB R2023b software platform. It was also shown that the output voltage remained unchanged with and without a load and up to 1200 ns of dead-time, which provides a simple implementation of the corresponding mathematical model. In the recommended interval of 600–1500 ns, the influence of the dead-time on the value of the output voltage amplitude is less than 10%. The validity of the proposed method was confirmed through the implementation of the experimental prototype, a 5 kW wireless power transmission system, and the obtained results were in accordance with the simulation results.

Keywords: wireless power transfer; dead-time; inverter; notch; sensitivity analysis

1. Introduction

In recent decades, wireless power transfer (WPT) technology has experienced significant progress, offering a convenient and efficient means of transferring electrical energy without physical connections. This technology has found applications in various areas, including electric vehicles, mobile devices, medical devices, and home electronic appliances. Using WPT technology eliminates the need for physical cables and connectors. The power from the charging pad on the ground (or other surfaces) sent to a receiver unit installed on the vehicle is transferred via an electromagnetic field. Therefore, drivers do not need to physically plug in the vehicle when the WPT is applied, which is a great convenience.



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Copyright: © 2024 by the authors. Licensee MDPI, Basel, Switzerland. This article is an open access article distributed under the terms and conditions of the Creative Commons Attribution (CC BY) license (https:// creativecommons.org/licenses/by/ 4.0/). WPT technology can support high-power charging, making it possible to recharge an electrical vehicle relatively quickly. This technology continues to be developed, with the goal of matching or exceed the charging speeds of traditional plug-in methods. WPT does not require a physical charging station at each parking spot. Instead, charging pads can be embedded in roads, parking lots, or other surfaces, providing more flexibility in deploying charging infrastructure. WPT standards like SAE J2954 are emerging, promoting compatibility among different vehicle brands and charging infrastructure providers. WPT systems are designed with safety features, such as automatic shutdown if foreign objects are detected on the charging pad, in order to ensure safety during the charging process.

Many studies have been conducted in this field, including power management [1], magnetic material design [2], coil optimization [3,4], etc. In separate studies [5,6], the WPT for IoT applications and the use of arrays to transfer power to freely moving objects were analyzed in detail.

In WPT systems, the inverter has a key role in converting direct current (DC) power into high-frequency alternating current (AC) power, which is then transmitted wirelessly. A typical inverter with insulated-gate bipolar transistor (IGBT) technology in a WPT system, which is crucial for the conversion of DC current to AC current for efficient wireless energy transmission, is described in refs [7–9]. The IGBTs are commonly used in power electronics due to their ability to handle high voltage and current levels. In a WPT inverter, IGBTs are employed, considering their switching capabilities and durability. Their primary function is to convert the incoming direct current into an alternating current, as this conversion is necessary for compatibility with the resonant circuit used in WPT systems. The inverter modulates the DC voltage to create a sinusoidal AC waveform that matches the resonant frequency of the system. The inverter with IGBTs is controlled with a microcontroller. These controllers generate the required switching signals for the IGBTs to regulate the output voltage and the frequency precisely. Advanced control algorithms are used to maintain optimal power transfer efficiency and to adapt to variable load conditions [7,9,10]. WPT systems often operate at high frequencies, typically in the range of tens to hundreds of kHz. The IGBTs switch at these frequencies, and they are capable of handling the rapid switching required for efficient power transfer.

During their operation, IGBTs can generate heat, especially at high power levels. Therefore, appropriate cooling mechanisms such as heatsinks or fans are required, which have been designed and integrated into inverters. Their role is to dissipate the heat, and thus to maintain regular working conditions.

During inverter design, particular attention is paid to the dead-time issue. Dead-time in two-phase inverters with IGBTs represents a crucial concept in power electronics control to prevent destructive and inefficient shoot-through currents [11]. In a two-phase inverter, there are typically two legs, each consisting of two IGBTs (high-side and low-side) that control the flow of current through a load. The dead-time refers to the intentional delay between turning off one IGBT in a phase leg and turning on its complementary IGBT. However, such a blanking period can affect the reliability, power quality, and losses of the system [11-18]. Furthermore, if issues associated with dead-time are not addressed appropriately, it may result in voltage distortions [11]. Additionally, switching losses can occur due to voltage polarity reversal [12]. The dead-time may cause issues related to phase errors, affecting the transmitted power. To minimize the dead-time effect, regulation methods based on buck converters have been proposed [11]. Still, these methods cannot completely eliminate the dead-time effect [12,13]. Compensation methods require precise current detection and a complex algorithm, while their performance is highly dependent on the system parameters [12,13]. The dead-time issues in WPT systems have been reported in ref. [15]. In refs [8,16], the dead-time effect in a WPT system is discussed briefly, and a control strategy is implemented on the dual-active bridge circuit to eliminate the effects of the dead-time.

Considering all these facts [19–28], this paper presents a detailed theoretical analysis and experimental verification of the dead-time effect on a WPT system in an inverter.

The main goal of this research is finding the optimal dead-time value in order to provide the maximum power transmission by reducing the losses and voltage distortion. This study was carried out to analyze the influence of dead-time on changes in amplitude and first voltage harmonics at the output of the inverter. This analysis is significant for the implementation of a specific mathematical model such as the charging of batteries when the output voltage changes.

The main contribution of this research to the literature data is reflected in the results related to the invariance of the output voltage, with and without a load, up to a dead-time value of 1200 ns. In the recommended interval of 600–1500 ns, the influence of the dead-time on the value of the output voltage amplitude is less than 10%, as will be shown in this paper.

This paper is organized as follows: the Introduction is followed by an analysis of the theoretical background of the dead-time issue and operational waveforms of a WPT system in Section 2. Section 3 presents am analysis of the resonant compensation network. The dead-time effects of the WPT systems in the experiments are shown in Section 4. Finally, the conclusion is presented in Section 5.

2. Dead-Time Effects of One Active Bridge WPT System

As it was mentioned, in WPT systems operating at high frequencies, the ratio of dead-time versus the operating period becomes more prominent, since the dead-time effect can cause several difficulties [29,30]. Some of these difficulties are listed below [31,32]:

- Efficiency—The dead-time affects the overall efficiency of the WPT system. If the dead-time is too short or too long, it can lead to increased power losses. A short dead-time may cause shoot-through current and increase switching losses, while a long dead-time can result in decreased power transfer efficiency due to extended periods of no power transfer [21,22].
- Power quality—The dead-time can influence the output waveform quality of the inverter. Improper dead-time management may lead to distorted voltage and current waveforms, which can affect the power factor and harmonic content of the system [23].
- Output voltage ripple—The dead-time can also contribute to the output voltage ripple. If the dead-time is not properly optimized, it may introduce voltage fluctuations in the output, thus affecting the stability of the WPT system [24].
- Electromagnetic interference (EMI)—Poorly managed dead-time can increase the electromagnetic interference emissions, which may interfere with other electronic devices and lead to compliance issues with electromagnetic compatibility (EMC) standards.
- Switch stress—Incorrect dead-time settings can subject these switches to higher stresses, potentially reducing their reliability and lifespan.
- Control complexity—Dead-time management requires precise control algorithms and sensing techniques. Implementing and tuning these control systems can add complexity to the overall design of the WPT system.

2.1. Switching Characteristics without the Dead-Time Effect

In this work, in two-phase inverters with IGBTs, the dead-time is considered as a mandatory parameter in order to prevent destructive and inefficient shoot-through currents [21].

Figure 1 shows the ideal switching characteristics (a) and the equivalent circuit operation (b) of two-phase inverters with IGBTs without dead-time. Cross-conduction occurs when the high-side and low-side IGBTs in the phase leg are turned on simultaneously. This results in a short circuit across the DC bus, causing excessive current flow, increased power losses, and potential damage to the IGBTs. However, this setup will be explained in further text as a part of the theoretical discussion in general.



Figure 1. Switching characteristics and the equivalent circuit operation of two-phase inverters without IGBT dead-time. (a) Characteristic signals for a two-phase inverter without IGBT dead-time. (b) Equivalent circuit operation of two-phase inverters.

The waveform V_{gs1} - V_{gs4} shows the gate pulses of the appropriate IGBT MOSFET switches TR_1 - TR_4 , while the quantities V_{a0} , V_{b0} indicate the voltages in points *a* and *b*. This setup presents the phase-legs inverter. The V_{ab} is the fundamental component of the sine wave of the inverter output voltage, while the I_{ab} is the sine current through the load impedance *Z*.

In this case, there are two operating modes: Mode A and Mode B:

- Mode A is applied to the interval from t_0 to t_1 : TR_1 and TR_4 are ON, TR_2 and TR_3 are OFF. The sine wave current is positive and flows through TR_1 and TR_4 . The output voltage V_{ab} is a positive load $+V_{DC}$ because V_{a0} is $V_{IN}/2$ and V_{b0} is $-V_{IN}/2$. The difference between V_{ao} and V_{bo} is V_{IN} .
- Mode B is applied to interval from t_1 to t_2 : TR_1 and TR_4 are OFF, TR_2 and TR_3 are ON. The sine wave current is negative and flows through TR_2 and TR_3 . The output voltage V_{ab} is a negative load $-V_{DC}$ because V_{a0} is $-V_{IN}/2$ and V_{b0} is $+V_{IN}/2$. The difference between V_{ao} and V_{bo} is $-V_{IN}$.

2.2. Switching Characteristics with the Dead-Time Effect

Figure 2 shows the switching characteristics (a) and the equivalent circuit operation (b) of the two-phase inverters with IGBTs dead-time. Parameter t_d refers to the dead-time interval between the complementary switching instances of the inverter.

During the dead-time, both the IGBTs in the inverter phase-leg are OFF, and the current flows through the IGBT body-diodes. If the current changes polarity during the dead-time, the pole voltages change polarities. The generation of a signal will be explained in terms of time modes (following order t_1 - t_2 , t_2 - t_3 , t_3 - t_4 , t_4 - t_5 , t_5 - t_6 , t_0 - t_1), as shown in Figure 2b:

- Mode 2: From t_1 to $t_2 \rightarrow$ Transistors TR_1 and TR_4 are turned ON and TR_2 and TR_3 are turned OFF, and the current i_{ab} flows from point *a* to point *b*, since the voltage at point *a* is positive and equal to $V_{dc}/2$, while at point *b*, it is negative and equal to $-V_{dc}/2$. In this case, the output voltage $V_{ab} = V_{dc}$.
- Mode 3: From t_2 to $t_3 \rightarrow$ All transistors are turned OFF. This is the effect of deadtime. The direction of the current i_{ab} remains the same as in mode 2. The current i_{ab}

flows through the anti-parallel diodes D_2 and D_3 ; therefore, the voltage at point *b* is $V_{dc}/2$, whereas the voltage at point *a* is $-V_{dc}/2$. Hence, the voltage at the output is $V_{ab} = -V_{dc}$.

- Mode 4: From t_3 to $t_4 \rightarrow$ All transistors are turned OFF. The current i_{ab} flows through the anti-parallel diodes D₁ and D₄ in the direction from point *b* to point *a*. The voltage at point *b* reached $V_{dc}/2$, and the voltage at point *a* reached $-V_{dc}/2$; thus, the output voltage is $V_{ab} = V_{dc}$.
- Mode 5: From t_4 to $t_5 \rightarrow$ The transistors TR₃ and TR₂ are turned ON. The current i_{ab} flows from point *b* to point *a*, the voltage at point *a* is $-V_{dc}/2$, and at point *b* is $+V_{dc}/2$. Hence, the output voltage is $V_{ab} = -V_{dc}$.
- Mode 6: From t_5 to $t_6 \rightarrow \text{All transistors are turned OFF. This is the effect of the dead$ $time. The inductor current <math>i_{ab}$ cannot change its direction; thus, it remains the same as in mode 5, and the diodes D_1 and D_4 conduct. The voltage pole of point *a* is positive + V_{dc} 2, while the pole of point *b* is negative $-V_{dc}/2$; thus, the output voltage is $V_{ab} = V_{dc}$.
- Mode 1: From t_0 to $t_1 \rightarrow$ All transistors are turned OFF. The current i_{ab} flows through the anti-parallel diodes D_2 and D_3 . The voltages at points *a* and *b* are $-V_{dc}/2$ and $+V_{dc}/2$, respectively. Therefore, the output voltage across the load is $V_{ab} = -V_{dc}$.



Figure 2. Switching characteristics and equivalent circuit operation of two-phase inverters with IGBTs dead-time. (a) Characteristic signals for a two-phase inverter with IGBTs dead-time. (b) Equivalent circuit operation of two-phase inverters.

Therefore, the dead-time in two-phase inverters with IGBTs is a critical component of inverter control strategies to ensure safe and efficient operation while minimizing waveform distortion and losses. However, dead-time in two-phase inverters can introduce significant challenges in achieving high efficiency and reliable power transfer. Deviations from rectangular pulses in voltage forms (Figure 2a) are the consequence of the dead time issue, and they influence the effective energy transfer. The next chapter addresses some of these challenges.

3. Modeling of WPT and System Analysis of Resonant Compensation Network

The configuration of the LCC-S resonant WPT system [4,7] is shown in Figure 3. The full-bridge inverter formed with four IGBTs (TR_1-TR_4) enables the DC input to be transformed into high-frequency AC power. The transmitting side consists of L_1 , L_f , C_f , and C_1 , where L_1 represents the primary resonant tank. This tank is tuned to have the same resonant frequency as the switching frequency of the full-bridge inverter. The high frequency AC power resonates in the primary resonant tank. The receiving side contains elements L_2 and C_2 , where L_2 represents the secondary resonant tank. To receive the power from the primary side, this tank must match the switching frequency of the full-bridge inverter. The high-frequency AC power is transmitted wirelessly through the main coupling between the main coils L_1 and L_2 , described with mutual coefficient inductance M. Afterwards, it is converted back to DC by the rectifier made of four diodes D_5 – D_8 and filtering capacitor C_0 .



Figure 3. The circuit of the WPT system with an LCC-S resonant compensation network.

The key properties of the LCC-S topology are:

- Series compensation: Series compensation networks are added to reduce the voltage distortion caused by the dead-time. This enhancement improves the control over the output voltage waveform, resulting in increased power transfer efficiency.
- Enhanced power quality: The LCC-S topology minimizes the harmonic generation and voltage distortion, ensuring that the output voltage complies with required power quality standards.
- Improved resonant behavior: The series compensation enhances the resonant behavior of the system, optimizing the wireless power transfer efficiency at the resonant frequency.

3.1. Calculation of the Phase Regulation Parameters of the WPT System with an LCC-S Resonant Compensation Network

The working principle of the investigated WPT system with an LCC-S resonant compensation network with a load is completely based on the phase regulation. Therefore, the parameters of the phase regulation were calculated using the equivalent electrical circuit shown in Figure 4.



Figure 4. The equivalent electrical circuit of the WPT system with an LCC-S resonant compensation network with a load.

The resistances of the coils and capacitors in the transmitting (R_1) and receiving part of the circuit (R_2) are marked as $R_1 = R_{C1} + R_{L1}$ and $R_2 = R_{C2} + R_{L2}$, respectively. The equation that connects the currents I_1 and I_2 is given as:

$$\underline{I}_{1}' = \frac{R_2 + R_{Load} + j(X_{L2} - X_{C2})}{jX_M} \underline{I}_2$$
(1)

Where X_{L2} is inductive reactance, X_{C2} is capacitive reactance, X_M is mutual reactance, and R_{Load} is resistance of the load.

The parameters of the transmission coil part of the circuit in Figure 4 are calculated as follows:

$$-jX_{C_f}(\underline{I}_1 - \underline{I}_1') = (R_1 + j(X_{L_1} - X_{C_1}))\underline{I}_1' - jX_M\underline{I}_2$$
⁽²⁾

and U_1 is determined as:

$$\underline{U}_1 = j \left(X_{L_f} - X_{C_f} \right) \underline{I}_1 + j X_{C_f} \underline{I}_1'.$$
(3)

Quantities X_{L1} and X_{Lf} are inductive reactances, while X_{C1} and X_{Cf} are capacitive reactances. Using expressions (1) and (2), the following relations can be derived:

$$-jX_{C_{f}}I_{1} + jX_{M}I_{2} = \left(R_{1} + j\left(X_{L_{1}} - X_{C_{1}} - X_{C_{f}}\right)\right)I_{1}'$$
(4)

$$\frac{-jX_{C_f}}{R_1 + j\left(X_{L_1} - X_{C_1} - X_{C_f}\right)}I_1 + \frac{jX_M}{R_1 + j\left(X_{L_1} - X_{C_1} - X_{C_f}\right)}I_2 = \frac{R_2 + R_{Load} + j(X_{L2} - X_{C2})}{jX_M}I_2$$
(5)

Based on expressions (4) and (5), the U_1 and I_1 are obtained as follows:

$$I_{1} = \left[\frac{\left(R_{1} + j\left(X_{L_{1}} - X_{C_{1}} - X_{C_{f}}\right)\right)\left(R_{2} + R_{Load} + j\left(X_{L2} - X_{C2}\right)\right)}{X_{M}X_{C_{f}}} + \frac{X_{M}}{X_{C_{f}}}\right]I_{2}$$
(6)

$$U_{1} = j \left(X_{L_{f}} - X_{C_{f}} \right) + X_{C_{f}}^{2} \frac{(R_{2} + R_{Load}) + j(X_{L2} - X_{C2})}{\left(R_{1} + j \left(X_{L_{1}} - X_{C_{1}} - X_{C_{f}} \right) \right) (R_{2} + R_{Load} + j(X_{L2} - X_{C2})) X_{M}^{2}} I_{1}$$

$$(7)$$

Using expressions (1), (6), and (7), the input impedance $\underline{Z}_{in} = \frac{\underline{U}_1}{\underline{I}_1}$ can be expressed as:

$$Zin_{1} = \frac{X_{C_{f}}^{2}(R_{1}+R_{Load})}{\left(R_{1}+j\left(X_{L_{1}}-X_{C_{1}}-X_{C_{f}}\right)\right)(R_{2}+R_{Load}+j(X_{L2}-X_{C2}))X_{M}^{2}} + j\left[\left(X_{Lf}-X_{Cf}\right) + \frac{X_{C_{f}}^{2}(X_{L2}-X_{C2})}{\left(R_{1}+j\left(X_{L_{1}}-X_{C_{1}}-X_{C_{f}}\right)\right)(R_{2}+R_{Load}+j(X_{L2}-X_{C2}))X_{M}^{2}}\right]$$
(8)

The inductors L_1 , L_2 , L_f and capacitors C_1 , C_2 are chosen in a way to achieve the resonance:

$$X_{L2} - X_{C2} = 0 (9)$$

$$X_{L_1} - X_{C_1} - X_{C_f} = 0 (10)$$

Finally, the ratio of the currents and the input impedance can be expressed as:

$$\frac{\underline{I}_{1}}{\underline{I}_{2}} = \frac{1}{X_{C_{f}}} \frac{R_{1}(R_{2} + R_{Load}) + X_{M}^{2}}{X_{M}}$$
(11)

$$\underline{Z}_{in} = \frac{X_{C_f}^{\ 2}(R_2 + R_{Load})}{R_1(R_2 + R_{Load}) + X_M^2} + j\left(X_{L_f} - X_{C_f}\right)$$
(12)

The phase angle α is given as:

$$\alpha = 2 \cdot \arccos\left(\frac{\pi}{2\sqrt{2}} \frac{U_{1_rms}}{U_{dc}}\right) \tag{13}$$

In order to verify this comprehensive theoretical analysis, a simulation of the operation of a WPT with an LCC-S topology was performed.

3.2. Analyzing a Wireless Power Transfer (WPT) System in MATLAB

One of the goals of the present study is to analyze and optimize the behavior of the investigated WPT system using simulations in MATLAB software. The theoretical model will be verified through simulations, and it will be used to obtain the parameters for the experimental setup.

The proposed model of a WPT system with an LCC-S resonant circuit is shown in Figure 5. The main component is the inverter, consisting of four IGBTs controlled in phase via four gates. The control block shown on the left side of Figure 5 is used for the frequency, phase, and dead-time setup. The model also includes a resonant compensation circuit (inductor L_f , capacitors Cf, C_{GA} , and C_{VA}), a transformer of transmission ratio of 1:1, a diode rectifier, and a resistive switching model.



Figure 5. Model of the WPT system with an LCC-S resonant compensation network in MATLAB.

The following quantities were selected: the input DC voltage is $U_{in} = 310$ V, the resonant frequency is f = 70 kHz, and the transfer gap is h = 100 mm. The parameters of the LCC-S resonant WPT system are listed in Table 1.

Parameter	Label	Value
Primary coil	L_GA	38.5 uH
Secondary coil	L_VA	46.4 uH
Mutual inductor	M	8.13 uH
Primary series capacitor	C_GA	210 nF
Secondary series capacitor	C_VA	115 nF
Primary parallel capacitor	Cf	375 nF
Primary series inductor	Ĺf	13.8 uH
Output equivalent resistance	Rload	22 Ω

Table 1. LCC-S resonant WPT system parameters.

Two methods are used for the measurement of the mutual inductance:

1. Using an impedance analyzer, when the transmitter and receiver are connected to each other via one coil (so that the winding direction is the same), the total inductance is measured. Furthermore, based on the measured total inductance, the mutual inductance is obtained using the following expression:

$$M = \frac{L_{total} - L_GA - L_VA}{2}.$$

2. The second method is applied before the induced EMS: The receiver is excited by a sinusoidal current of amplitude *I* and frequency *f*, and the amplitude of the induced voltage *U* is measured at the open transmitter. Based on these values, the mutual inductance is calculated as:

$$M = \frac{U}{2\pi fI}$$

Both methods gave the same result for the mutual inductance, which can be seen in Table 1 (M = 8.13 uH).

Figure 6 shows the inverter's output voltage and current. Observing Figure 6a at the bottom of the diagram, several strange shapes as a short-lived peak in the voltage can be noticed. This phenomenon is a consequence of dead-time existence. Several papers provide a detailed analysis of this phenomenon [5–8], which is usual for the given settings.



Figure 6. (a) Inverter output voltage waveform; (b) inverter output current waveform.

Figure 7 shows the graph of the output voltage U_{out} in relation to the value of the dead-time. The red curve represents the output voltage with R_{load} , while the blue curve represents the output voltage without R_{load} . In both cases, the system behaves in a similar way. Namely, the output voltage remains unchanged with and without the load up to 1200 ns of dead-time, which is significant. This provides a simple implementation of

the mathematical model. The behavior of voltage at higher dead time values is a direct consequence of the existence of dead-time. Therefore, the recommended interval of the dead-time is 600–1500 ns. A lower side time limit corresponds to the IGBT turn off time, and the upper side restriction is due to the change in amplitude behavior, which is less than 10%.



Figure 7. Effect of the dead-time on the output voltage.

In the literature [24–26,29] related to a similar topic, the absence of an analysis of the output voltage behavior with and without a load as a function of the dead-time is revealed. This makes the conducted measurements significant.

The dead-time is typically implemented in the control algorithm of the inverter [27]. The microcontroller responsible or the inverter control calculates and enforces the appropriate dead-time delays based on the received switching commands. The amount of required dead-time can vary based on several factors such as the characteristics of the IGBTs, the voltage and current levels, and the desired switching frequency. To account for variations in the operating conditions, the dead-time is frequently and dynamically adjusted. While dead-time is necessary to prevent shoot-through, excessive dead-time can lead to increased switching losses and reduce the overall efficiency. Therefore, to maintain a high inverter efficiency, a compromise between ensuring adequate dead-time and minimizing its duration needs to be accomplished.

3. Experimental Results and Discussion

In order to obtain an appropriate value of the switching dead-time in the LCC-S resonant WPT system, an experimental prototype was realized. The LCC-S resonant circuit is a key element in this prototype. It consists of inductors and two capacitors on the transmitter side and of capacitors on the receiver sides. The LCC-S configuration helps in achieving efficient power transfer by minimizing losses and maximizing coupling between the transmitter and receiver.

The LCC resonant circuit operates at its resonant frequency, which is determined based on the values of the inductors and capacitors. Bringing the transmitter and receiver in close proximity ensures their tuning to the same resonant frequency. This ensures maximum energy transfer between the two sides of the circuit.

The theoretical model is verified through the simulations used for obtaining the parameters for the experimental setup. The inverter is designed to work in conjunction with the resonant network of the WPT system. It synchronizes its output frequency with the resonant frequency of 70 kHz to maximize the power transfer efficiency. The experimen-

tal platform, a prototype of a WPT system with an LCC-S resonant circuit, is shown in Figure 8a. This is an advanced wireless charging system that leverages resonant technology to efficiently transfer electrical power from a source (transmitter) to a device (receiver).





Figure 8. Experiment platform. (**a**) Prototype of the WPT system; (**b**) elements of the inverter with a special driver and a half-bridge made with IGBTs.

The transmitter unit is responsible for generating and transmitting the wireless power. It consists of the following elements shown in Figure 8b:

- 1. Three-phase bridge rectifier MDS150A1600V [33]: The rated current of this module is 150 A, and the maximum allowed working voltage is 1600 V.
- 2. Soft start circuit for capacitor charging in the DC circuit: When the inverter is switched on, the capacitors in the DC circuit are charged through resistors that limit the initial current (initial charge current) and thus protect the diode rectifier. After a certain time, the resistors are bridged. The delay is realized by a time relay. The capacitor charging resistors are $2 \times 150 \Omega/25$ W, connected in parallel.
- 3. Capacitors in the DC circuit: The total capacity of the capacitors is 940 μ F, and the breakdown voltage is 800 V. In the DC circuit, the resistors are placed, and they provide the discharge of the capacitor after the inverter is turned off. The total resistance value is 22 k Ω , with a power of 18 W. The leakage current through these resistors for a voltage of 310 V is approximately 14 mA, while for a voltage of 570 V, the leakage current is approximately 25 mA.
- 4. Special power supplies for electronics (15VDC) and power supplies for relays, which are used for the soft-charge circuit (24VDC).
- 5. Circuit for generating the dead-time for the operation of the IGBTs: This dead-time can be fine-tuned with multi-turn potentiometers.
- 6. Inverter: The inverter is part that contains the driver board EVAL-1ED3491Mx12M [34] and IGBT modules [35]. The driver board EVAL-1ED3491Mx12M is a single-channel isolated gate driver integrated circuit with an adjustable DESAT (Precise V_{CE}sat detection) and soft-off.

All the energy connections in the inverter are made of a strip of copper conductors of size 10×1 mm. An IGBT module (half-bridge) manufactured by TOSHIBA, marked MG50Q2YS50, with a rated collector current of 50 A and a maximum collector–emitter DC voltage of 1200 V was used for testing and manufacturing the inverter. The IGBT switch-on time is 200 ns, and the switch-off time is 600 ns. The dead-time is set to be longer than the IGBT turn-off time.

It was determined that the dead time can be within the range of 600 ns to 2000 ns according to Figure 7, where the simulated influence of the dead time is presented. To ensure the reliable functioning of the inverter WPT system with minimal voltage distortions,

a dead time value of 1500 ns was experimentally appointed. By choosing this dead time value, the corresponding effective power on the consumer is obtained, which means that the transmission losses are negligible in relation to the power intensity.

The graphs of the output voltage and current of the inverter circuit with a set dead time value of 1500 ns are shown in Figure 9a,b. The current waveform has a sinusoidal shape with an amplitude of 78 A. The effective current value is 55 A. For the maximum power, the transmission is 1.6 kW, the tuned resonant frequency is 70 kHz, and the angle of the phase regulation is 80°. Furthermore, certain deviations from rectangular pulses in voltage forms, which are consequence of the dead-time issue and influence the effective energy transfer, can be observed.



Figure 9. Voltage and current of the inverter circuit. (**a**) The waveform of the voltage of the transmitting coil. (**b**) The waveform of the current and voltage of the transmitting coil.

When choosing the optimal value of the dead-time, all the following effects were considered:

- Efficiency—a dead-time of 1500 ns did not affect the overall transmission efficiency.
- Power quality—the influence of the dead-time did not affect the quality of the output voltage waveform on the inverter or the stability of the WPT transmission.
- Electromagnetic interference (EMI)—the emission of electromagnetic disturbances as a result of the dead-time is aligned with the electromagnetic stability standards. In the proposed system, in the area outside the coils, the magnetic induction values according to the simulation results were lower than the values recommended by the ICNIRP guidelines.
- Switch stress—the selection of the dead-time considered the maximum possible operating frequency of the IGBTs.

Finally, it can be concluded that the analysis carried out in MATLAB is in agreement with the experimental results. Furthermore, considering its practical use, this WPT implementation can find applications in the process of charging lithium-ion batteries according to the principle of constant current–constant voltage.

4. Conclusions

The procedure used to minimize dead-time effects is explained in detail in this paper. Also, the dead-time adjustment method is applied and investigated in a practical example of wireless transmission. The regulation of dead-time is performed in order to achieve the highest possible power for the given phase angle. In particular, the minimum dead-time due to the switching-off of the IGBTs must be considered in practice.

The dead-time issue in two-phase inverters is a critical factor affecting the performance of two-phase wireless power transfer systems. The compensation topologies, such as the LCC-S, offer a promising solution to reduce the adverse effects of the dead-time, improving

the efficiency, power quality, and overall system performance. The primary contribution of this research to the existing findings lies in the conclusion drawn regarding the consistent output voltage, irrespective of the presence or absence of a load, up to a dead time value of 1200 ns. Within the suggested range of 600–1500 ns, the impact of dead time on the output voltage amplitude is observed to be less than 10%. Since WPT technology is still developing, addressing the challenges associated with the dead-time issue could be crucial for unlocking its full potential in various applications.

5. Future Works

Future works will focus on further optimization of the compensation topologies for two-phase inverters. Additionally, the analysis of advanced control strategies and the integration of emerging semiconductor devices in order to minimize the dead-time and enhance the WPT system performance in two-phase configurations should be investigated.

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